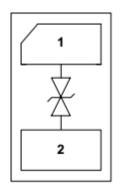


Description

The JE12B1LD20-2 is a 12V bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The JE12B1LD20-2 complies with the IEC 61000-4-2 (ESD) with ± 30 kV air and ± 30 kV contact discharge. It is assembled into an ultrasmall lead-free DFN1006-2 package. The small size and high ESD surge protection make JE12B1LD20-2 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Circuit Diagram



Circuit and Pin Schematic

Marking Diagram



Transparent top view

22:Device Marking Code

Features

- * 180W peak pulse power (8/20µs)
- * Low leakage:nA level
- * Operating voltage: 12V
- * Low clamping voltage
- * One power line protects
- * Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV

Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 8A (8/20μs)
- * RoHS Compliant
- * Package:DFN1006-2

Applications

- * Cellular Handsets and Accessories
- * Personal Digital Assistants
- Notebooks and Handhelds
- * Portable Instrumentation
- * Digital Cameras
- Peripherals
- * Audio Players

Ordering Information

Part Number	Packaging	Reel Size	
JE12B1LD20-2	10000/Tape & Reel	7 inch	



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

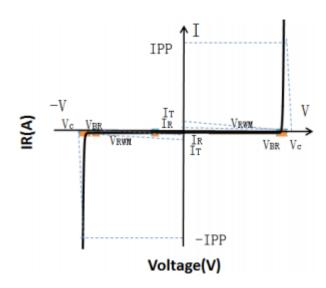
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20μs)	Ppk	180	W	
Peak Pulse Current (8/20μs)	IPP	8	A	
ESD per IEC 61000-4-2 (Air)	VECD	±30	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±30		
Operating Temperature Range	TJ	-55to +125	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Reverse Working Voltage	Vrwm				12	V
Breakdown Voltage	VBR	$I_T = 1 \text{mA}$	13.3			V
Reverse Leakage Current	I_R	$V_{RWM} = 12V$			0.2	uA
Clamping Voltage	Vc	$I_{PP} = 1A (8 \times 20 \mu s \text{ pulse})$			15.5	V
Clamping Voltage	Vc	$I_{PP} = 8A (8 \times 20 \mu s \text{ pulse})$			22.5	V
Junction Capacitance	Сл	VR = 0V, f = 1MHz,			30	pF

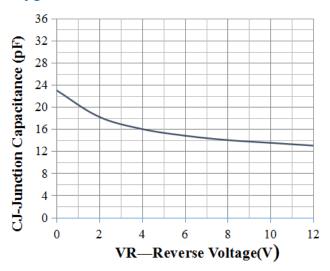
Portion Electronics Parameter

Symbol	Parameter	
Iτ	Test Current	
Ірр	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @Ic	

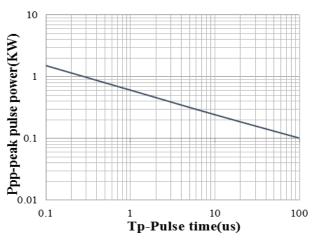




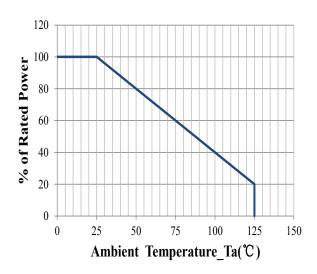
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



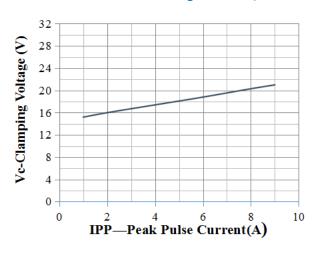
Junction Capacitance vs. Reverse Voltage



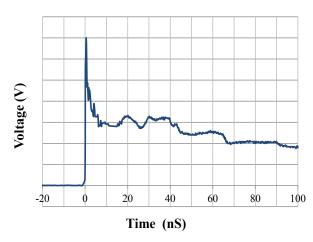
Peak Pulse Power vs. Pulse Time



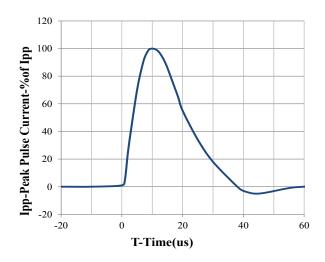
Power Derating Curve



Clamping Voltage vs. Peak Pulse Current



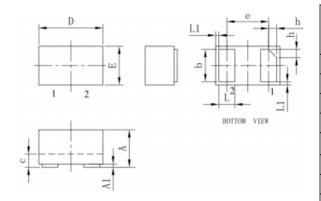
IEC61000-4-2 Pulse Waveform



8 X 20us Pulse Waveform

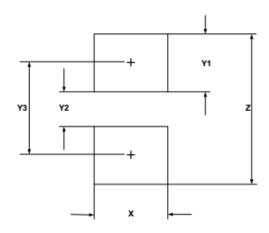


DFN1006-2 Package Outline Drawing (Dimensions in millimeters)



	DIMENSIONS					
	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
С	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
е	0.65 BSC			0.026 BSC		
E	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.05REF			0.002REF		
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern



SYM	DIMENSI	SIONS		
STW	MILLIMETERS	INCHES		
Х	0.60	0.024		
Y1	0.50	0.020		
Y2	0.30	0.012		
Y3	0.80	0.032		
Z	1.30	0.052		

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